ELECTROCONDUCTIVE DEVICE,

ORGANIC ELECTROLUMINESCENCE DEVICE

USING THE DEVICE AND

PROCESS FOR PRODUCING THE ELECTROCONDUCTIVE DEVICE

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FIELD OF THE INVENTION AND RELATED ARAT

The present invention relates to an organic electroluminescence (EL) device for use in, e.g., flat panel displays, projection displays, and printers; an electroconductive device used for the EL device; and a process for producing the electroconductive device.

Since T.W. Tang et al substantiated in 1987 that it is possible to effect high-brightness

luminescence under application of a low DC voltage by utilizing a lamination structure comprising a film of fluorescent metal chelate complex and a diamine-based molecular film, an applied study on an organic electroluminescence (EL) device as a luminescence

device with high-speed responsiveness and high efficiency has been extensively conducted. The organic EL device is a self-light emitting device of a carrier injection type using luminescence occurring at the time of re-combination of electrons and holes reached to a luminescent layer.

Figure 6 shows a structure of an ordinary organic EL device.

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Referring to Figure 6, the EL device includes a transparent substrate 21, and thereon layers of a transparent electrode 22, a hole transporting layer 23, a luminescent layer 24 and a metal electrode 25 are successivel χ disposed in this order. Between the metal electrode 25 (as a cathode) and the transparent electrode 22 (as an\anode) for taking out emitted light, organic compound layers 20 comprising the luminescence layer 24 and the hole transporting layer 23 are formed and disposed each in a thickness of ca. several hundred A. Examples of the cathode metal electrode 25 may include a metal or an alloy having a smaller work function, such as aluminum, aluminumlithium alloy and magnesium-silver alloy. Examples of the anode transparent electrode \$2 may include an electroconductive material having a larger work function, such as ITO (indium tin oxide). The organic compound layer 20 in this structure (Figure 6) has two-layer structure comprising the luminescence layer 24 and the hole transporting layer 23.

Figure 7 shows another structure of an ordinary organic EL device.

Referring to Figure 7, the EL device includes a transparent substrate 21 on which a transparent electrode 22 (anode), a hole transporting layer 23, a luminescence layer 24, an electron transporting layer 31 and a metal electrode 25 (cathode) are sequentially

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disposed in this order. In this case, an organic compound layer 20 has a three-layer structure comprising the hole transporting layer 23, the luminescence layer 24 and the electron transporting layer 31.

Generally, the hole transporting layer (23 in Figures 6 and 7) has a function of efficiently injecting holes from the anode (transparent electrode 22) into the luminescence layer (24). On the other hand, the electron transporting layer (31 in Figure 7) generally has a function of efficiently injecting electrons from the cathode (metal electrode 25) into the luminescence layer (24).

These hole transporting and electron transporting layers (23 and 31) also have an electron (carrier) blocking function and a hole (carrier) blocking function, respectively, thus enhancing a resultant luminescence efficiency.

For these carrier (hole and electron)

transporting layers (23 and 31), it is important to exhibit a sufficient charge (carrier) transporting ability, particularly a carrier mobility.

Accordingly, if the carrier mobility in the carrier transporting layer is increased, more carriers can be injected into the luminescence layer 24 to enhance the luminescence efficiency. In addition, the higher mobility is also effective in increasing a

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thickness (e.g., ca. 1 μm) of the carrier transporting layer (generally, several hundred A-thick). As a result, it becomes possible to prevent an occurrence of short circuit between the pair of electrodes (anode and cathode) and improve a productivity.

For this reason, at present, a compound (material) for the carrier transport layer has been extensively developed in order to achieve a high luminescence efficiency of the organic EL device.

In order to obtain a high electroconductivity by applying an electric field to a pair of electrodes between which an organic compound layer is disposed, it is necessary to provide a good carrier (electron/hole) injection performance from the electrodes and a high carrier mobility.

Incidentally, although hole injection/transport materials exhibiting relatively good performances have been proposed, an electron injection/transport material exhibiting a sufficient characteristic has not been found as yet.

SUMMARY OF THE INVENTION

In view of the above-mentioned problem, an object of the present invention is to provide an electroconductive device using a carrier injection and/or transport layer comprising a material suitable for efficiently injecting and/or transporting carriers

(holes or electrons).

Another object of the present invention is to provide an organic electroluminescence (EL) device including the electroconductive device and having a high luminescence efficiency and a high reliability.

A further object of the present invention is to provide a process for producing the electroconductive device.

According to the present invention, there is provided an electroconductive device, comprising: a pair of oppositely disposed electrodes, and a luminescence layer and an electroconductive layer disposed between the electrodes, wherein

the electroconductive layer comprises a mixture of a plurality of organic compounds which are mutually structural isomers and include a major component and a minor component, the mixture comprising the major and minor components in a (major component)/(minor component) ratio of 1/1 to 9/1.

According to the present invention, there is also provided an electroluminescence (EL) device including the above-mentioned electroconductive device wherein the electroconductive layer is used as a carrier injection layer and/or a carrier transport layer.

According to the present invention, there is

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further provided a process for producing the abovementioned electroconductive device, comprising:

a step of forming the above-mentioned electroconductive layer between the pair of electrodes.

These and other objects, features and advantages of the present invention will become more apparent upon a consideration of the following description of the preferred embodiments of the present invention taken in conjunction with the accompanying drawings.

BRIEF DESCRIPTION OF THE DRAWINGS

Figure 1 is a schematic sectional view of an embodiment of an electroconductive device (organic EL device) prepared in Example 2 (appearing hereinafter) according to the present invention.

Figures 2 and 3 are respectively a graph showing a current (density)-voltage characteristic of an organic EL device prepared in Example 2 (Figure 2) and Comparative Example 1 (Figure 3), respectively.

Figures 4 and 5 are respectively a graph showing a luminescence efficiency of an organic EL device prepared in Example 2 (Figure 4) and Comparative Example 1 (Figure 5), respectively.

Figures 6 and 7 are respectively a schematic

sectional view of an embodiment of an organic EL device.

DESCRIPTION OF THE PREFERRED EMBODIMENTS

The electroconductive device according to the present invention is characterized in that an electroconductive layer disposed between a pair of electrodes is formed by using a mixture of a plurality of organic compounds which are mutually structural isomers and include a major component and a minor component (hereinafter, referred to as a "structural isomer mixture"). The structural isomer mixture comprises the major and minor component in (major component)/(minor component) ratio of 1/1 to 9/1, preferably 1/1 to 5/1.

The organic EL device according to the present invention using the electroconductive layer as a carrier injection layer and/or a carrier transport layer, preferably as an electron injection layer and/or an electron transport layer.

Herein, the structural isomers refer to compounds having an identical ring structure and an identical rational formula but having (molecular) structures different in the manner in which their atoms are linked.

A compound molecule having at least one ring structure has a planar molecular structure by nature,

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thus being liable to be crystallized in the case of a single compound (free from structural isomer).

On the other hand, we have found that it is possible to stably forming an amorphous structure by using an structural isomer mixture, particularly a mixture of low-molecular compounds each having such a ring structure that a plurality of rings are connected via a single bond.

In the present invention, by using the structural isomer mixture having such a stabilized amorphous structure, it becomes possible to form an electroconductive layer exhibiting a high carrier injection and/or transport performance. Further, by using the electroconductive layer as a charge injection and/or transport layer, it is possible to provide an organic EL device with a high luminescence efficiency.

Incidentally, with respect to a luminescent layer, it has been suggested that the luminescent layer containing an aminoquinoline complex having a facial-rich stereostructure provides better performances (Japanese Laid-Open Patent Application (JP-A) No. 4-85388).

According to the present invention, by using the structural isomer mixture in the electroconductive layer (as the carrier injection and/or transfer layer, the resultant EL device exhibits an excellent

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luminescent characteristic.

In the present invention, the organic compounds constituting the structural isomer mixture may preferably be represented by the following formula (1):

$$(R-X)_{n}-Ar-(X'-R')_{m} \qquad (1),$$

wherein Ar denotes a connected ring structure comprising two single rings connected with each other via a single bond or two fused rings connected with each other via a single bond; X and X' independently denote a single bond, -O-, -S-, -OOC- or -COO-; R and R' independently denote -H, -F or a linear or branched alkyl group having 1 - 20 carbon atoms capable of including one methylene group which can be replaced with -O-, -S-, -CH=CH- or -C=C-; and m and n are an integer of 1 - 8, with the proviso that R and R' cannot be -H at the same time when X and X' are a single bond.

In the formula (1), Ar may preferably be a

connected ring structure comprising two fused rings

connected with each other via a single bond, wherein

each of said two fused rings comprises 2 - 5 rings.

Further, Ar in the formula (1) may preferably be a

connected ring structure represented by any one of the

following formulas (a) to (n):

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(l)

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wherein CH is optionally substituted with N or NH, and ${\rm CH_2}$ is optionally substituted with S or O.

Ar in the formula (1) may preferably be a connected ring structure represented by the following formula (2):

A-B (2),

wherein A and B independently denote any one of phenyl-diyl, pyridine-diyl, pyrazine-diyl, pyrimidinediyl, pyridazine-diyl, indene-diyl, indolizine-diyl, isoindole-diyl, indole-diyl, purine-diyl, naphthalenediyl, quinoline-diyl, isoquinoline-diyl, quinoxalinediyl, 1,5-naphthyridine-diyl, 1,6-naphthyridine-diyl, 1,7-naphtharidine-diyl, 1,8-naphthyridine-diyl, quinazoline-diyl, cinnoline-diyl, pyrido[2,3b]pyrazine-diyl, pyrazino[2,3-b]pyrazine-diyl, pteridine-diyl, biphenylene-diyl, fluorene-diyl, carbazole-diyl, thianthrene-diyl, phenalene-diyl, phenanthridine-diyl, phenanthrene-diyl, anthracenediyl, chrysene-diyl, acridine-diyl, perimidine-diyl, phenanthroline-diyl, phenazine-diyl, phenothiazinediyl, phenoxathin-diyl, indan-diyl, coumaran-diyl, phthalan-diyl, chroman-diyl, isochroman-diyl, thiachroman-diyl, isothiachroman-diyl, and thiaxanthene-diyl.

In the formula (2), A may preferably be quinoxaline-diyl.

In the formula (1) and (2), R=R', X=X', m=n=1

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are satisfied in the formula (1), and A=B may preferably be satisfied to form a symmetric structure having a center of symmetry.

The organic compounds used for constituting

the structural isomer mixture in the present invention
may desirably be selected based on the following
molecular design factors (1) to (3).

(1) Lowering in LUMO (lowest unoccupied molecular orbital) level

A electron transport is effected by hopping conduction on LUMO of organic compound molecules. Accordingly, it is important to improve electron injection from an electrode to LUMO. Generally, in view of chemical stability of the electrode, it is difficult to decrease a work function of the electrode. As a result, a key feature for the improved electron injection is how to lower the LUMO level of organic compounds used.

HOMO (highest occupied molecular orbital) levels and LUMO levels of several ring structures (capable of constituting the organic compounds used in the present invention) according to molecular orbital method in order to expect the LUMO level of the organic compounds. As the molecular orbital method, in the present invention, a semiempirical molecular orbital method (the AM1 method) is used.

The results are as follows.

			HOMO	LUMO
5	N	quinoline	-9.2	-0.47
	N	isoquinoline	-9.0	-0.56
10		quinoxaline	-9.6	-0.68
	$N \longrightarrow N$	[1,5]naphthyridine	-9.7	-0.67
15	N_N	[1,6]naphthyridine	-9.5	-0.77
20	N-N	[1,7]naphthyridine	-9.5	-0.76
		[1,8]naphthyridine	-9.8	-0.71
25	N N	quinazoline	-9.5	-0.77

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As shown above, compared with naphthalene, naphthalene skeleton having 1 - 4 nitrogen atoms (substituted for corresponding CH group(s) of naphthalene) can lower the LUMO level of naphthalene.

Accordingly, by using such heterocyclic fused ring structure as a skeleton of organic compound, a resultant electron injection performance from an electrode is expected to be improved based on lowering in LUMO level.

(2) Symmetry of molecular structure

As described in (1), the electroconductivity of liquid crystal compound is based on the hopping conduction, which varies largely depending on a magnitude of overlap integral of π electron cloud between adjacent molecules. It is important to increase the overlap integral of the π electron cloud

in order to improve an electron conductivity. For the electron conduction, it is effective to impart a (molecular-structural) symmetry to the organic compound molecules so as to dispose their π electron skeletons close to each other, thus increasing the overlap integral of π electron cloud. As a result, a mobility of electron is improved to provide an enhanced electroconductivity.

Even if a complete symmetry of molecular

structure is not ensured, the above advantages are
retained as far as organic compound molecules have a
similar skeleton structure such that both of terminal
chains have an almost equal carbon number.

Accordingly, in the present invention, the

15 organic compounds may preferably have a symmetric

structure having a center of symmetry by designing

molecular structure so as to satisfy R=R', X=X', m=n=1

and A=B (in A-B as Ar) in the above-mentioned formulas

(1) and (2).

20 (3) Suppression of crystallization in the presence of structural isomers

The increase in overlap integral of $\boldsymbol{\pi}$ electron cloud between adjacent molecules leads to an increase in regularity of mutually adjacent molecules, thus resulting in a high crystallinity thereof.

In order to prevent an occurrence of such a crystallization, it is expected that the crystallinity

of the structural isomer mixture can be lowered by mixing a plurality of organic compounds having different substituents outside the π electron clouds, thus providing an amorphous property to increase an electroconductivity.

Accordingly, the structural isomer mixture constituting the electroconductive layer used in the present invention may desirably be placed in an amorphous state.

In the present invention, the above-described three molecular design factors (1), (2) and (3) are not necessarily fulfilled at the same time.

Based on the above molecular design factors, we have found that it is possible to realize a luminescence device with a high luminescence efficiency by using the structural isomer mixture comprising a plurality of organic compounds of the formula (1) (preferably formula (2)) in a carrier injection and/or transport layer of an organic EL device.

Particularly, when an electron injection layer is formed by using the structural isomer mixture comprising such organic compounds based on the above molecular design factors, it becomes possible to considerably improve an electron injection performance.

The luminescence device (electroconductive

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device) with a high luminescence efficiency can be applied to products required to effect energy saving or provide a high luminance (brightness), such as a display apparatus, an illumination apparatus, a light source for a printer, and a backlight for a liquid crystal display apparatus. More specifically, as the display apparatus, it is possible to provide a flat panel display excellent in energy saving performance, visibility and weight reduction. As the light source for a printer, it is possible to replace a laser light source of a laser beam printer widely used at present with the electroconductive device of the present Image formation may be performed by invention. disposing independently addressable devices in array and subjecting a photosensitive drum to a desired exposure to light. By using the electroconductive device of the present invention, it is possible to remarkably reduce an apparatus size (volume). respect to the illumination apparatus and the backlight, it is possible to expect an energy saving performance by the use of the electroconductive device of the present invention.

Hereinbelow, specific but non-exhaustive examples of the organic compounds of the formula (2) constituting the structural isomer mixture used in the electroconductive device (or EL device) of the present invention will be enumerated in the following Tables 5

- 15. Symbols a_1 to a_{33} used for specifying a ring structure for liquid crystal compounds shown in Tables 5 - 15 have specific skeletons (ring structures) shown in the following Tables 1 - 4.

Table 1

1	Symbol	Name	Formula
10	a ₁	quinoxaline-diyl	N=N
	a ₂		N—N—
15	a ₃	quinoline-diyl	N.
	a ₄		N-\
20	a ₅	isoquinoline-diyl	N N
	a ₆		N N
25	a ₇	quinoline-diyl	N N
	a ₈		N-\\

Table 2

	Symbol	Name	Formula
5	a ₉	[1,5]naphthyridine-diyl	N-N-N-
	a ₁₀	[1,6]naphthyridine-diyl	N N
10	a ₁₁		N—N
	a ₁₂	[1,7]naphthyridine-diyl	N=_N
15	a ₁₃	v.	N—N—N
	a ₁₄	[1,8]naphthyridine-diyl	
20	a ₁₅	quihazoline-diyl	N N
	a ₁₆		N— N—
25	a ₁₇	cinnoline-diyl	, N

Table 3

į	Symbol	Name	Formula
5	a ₁₈	cinnoline-diyl	N, N
10	a ₁₉	pyrido[2,3-b]pyridine-diyl	N—N—N
10	a ₂₀		N—N
	a ₂₁	pyrido[2,3-b]pyrazine-diyl	N-N-N
15	a ₂₂		N—N
20	a ₂₃	pyrazino[2,3-b]pyrazine-diy]	N N N
	a ₂₄	pteridine-diyl	N—N—N
25	a ₂₅		N—N—N—

Table 4

		Symbol	Name	Formula
	5	a ₂₆	naphthalene-2,6-diyl	
	10	a ₂₇	chrycene-2,6-diyl	
iš		a ₂₈	phënazihe-diyl	N=\
	15	a ₂₉	isochroman-diyl	
		a ₃₀	phenoxathiin-diyl	S S
	20	a ₃₁	phenanthroline-diyl	N-N-N-
		a ₃₂	pyrazine-diyl	N—N—
	25	a ₃₃	[1,8]naphthyridine-diyl	N—N—

Table 5

	No.	R	X	Α	В	X'	R'
	1	CH ₃	0	a 1	a 1	-	$C_{7}H_{15}$
	2	C ₈ H ₁₇	_	a 1	a 1	_	$C_{11}H_{23}$
Ī	3	F	_	a 1	a 1		$C_{20}H_{41}$
	4	Н	_	a 1	a 1	0	OC_9H_{19}
Ī	5	C₄H ₉	0	a ₁	a ₁		C ₈ H ₁₇
	6	$C_{12}H_{25}$	0	a 1	a ı	<u>.</u>	$C_{10}H_{21}$
	7	C ₆ H ₁₃	0	a 1	a ₁	0	C_6H_{13}
	8	C ₈ H ₁₇	0	a 1	a 1	0	C_8H_{17}
	9	C ₁₁ H ₂₃	0	a 1	a 1	0	$C_{11}H_{23}$
	10	C ₄ H ₉ OCH(CH ₃)CH ₂ (CH ₂) ₄	0	a 1	a 1	0	(CH ₂) ₄ CH ₂ CH(CH ₃)OC ₄ H ₉
	11	C ₉ H ₁₉	0	a ₁	a 1	0	(CH₂)₅OC₃H₁
	12	$C_5H_{11}OCH_{23}$	0	a 1	a 1	0	$(CH_2)_3OC_5H_{11}$
	13	C_5H_{11}	0	a 1	a ₁	0	$C \equiv CC_6H_{13}$
	14	C ₅ H ₁₁ CH=CH	0	a ₁	a 1	О	CH=CHC₅H₁1
	15	$C_{10}H_{21}$	S	a 1	a 1	S	$C_{10}H_{21}$
	16	C ₃ H ₇	_	a ₁	a 1		$\mathrm{C_3H_7}$
	17	C ₄ H ₉	_	a ₁	a ₁	_	C₄H ₉
	18	C_5H_{11}	_	a ₁	a ₁	_	C_5H_{11}
	19	C ₆ H ₁₃		a ₁	a ₁		C_6H_{13}
	20	C ₇ H ₁₅		a ₁	a ₁		C ₇ H ₁₅

Table 6

No.	R	X	Α	В	X'	R'
21	C ₈ H ₁₇	_	a 1	a ₁	_	C ₈ H ₁₇
22	C ₉ H ₁₉	_	a ₁	a 1		C_9H_{19}
23	$C_{10}H_{21}$		a 1	a ₁	_	$C_{10}H_{21}$
24	$C_{11}H_{23}$		a 1	a ₁	_	C ₁₁ H ₂₃
25	$C_{12}H_{25}$		a 1	a ₁	_	$C_{12}H_{25}$
26	C ₁₈ H ₃₇	_	a 1	a 1	_	$C_{18}H_{37}$
27	C_6H_{13}	_	a 1 .	a ₁	_	C_8H_{17}
28	C ₁₁ H ₂₃	_	a 1	a 1		$\mathrm{C_3H_7}$
29	C_6H_{13}	COO	a 1	a 1	OOC	C_6H_{13}
30	C_5H_{11}	COO	a 1	a 1	COO	$C_{11}H_{23}$
31	C ₂ H ₅ CH(CH ₃)CH ₂ (CH ₂) ₄	OOC	a 1	a 1	COO	$(CH_2)_5CH(CH_3)C_2H_5$
32	Н	_	a 1	a 26	0	C_4H_9
33	C_8H_{17}	_	a 1	a ₂₆	0	C ₅ H ₁₁
34	C ₁₁ H ₂₃	_	a 1	a 26	0	C ₁₀ H ₂₁
35	C_9H_{19}	0	a 1	a 26	0	C ₉ H ₁₉
36	C ₁₅ H ₃₁	0	a ₁	a 26	0	C ₇ H ₁₅
37	C ₁₃ H ₂₇	_	a 1	a 26		C ₃ H ₇
38	C ₆ H ₁₃	_	a 1	a 26	_	C ₆ H ₁₃
39	C ₉ H ₁₉	. —	a 1	a 26		C ₉ H ₁₉
40	$\mathrm{C_3H_7}$	0	a ₂	a 2	0	C ₁₄ H ₂₉

Table 7

No.	R	X	Α	В	Χ'	R'
41	C ₇ H ₁₅	_	a 2	a ₂		С7Н15
42	$C_{12}H_{25}$	_	a 2	a 2	_	C ₁₈ H ₃₇
43	Н	_	a 2	a 26	0	C_4H_9
44	C ₈ H ₁₇	-	a 2	a ₂₆	_	$C_{11}H_{23}$
45	C_5H_{11}		a 2	a ₂₆	0	(CH ₂) ₅ OC ₆ H ₁₃
46	C_2H_5	0	аз	a 3	_	C ₈ H ₁₇
47	C ₆ H ₁₃	_	аз	a 3	-	C_6H_{13}
48	C_7H_{15}		аз	a 3	_	$\mathrm{C_{7}H_{15}}$
49	C ₈ H ₁₇	_	аз	a 3	_	C_8H_{17}
50	$C_{12}H_{25}$	_	аз	a 3	_	$C_{12}H_{25}$
51	C_9H_{19}	0	аз	a 3	0	$\mathrm{C_{5}H}_{11}$
52	$C_{10}H_{21}$	_	аз	a ₂₆	0	C_4H_9
53	C_5H_{11}	_	a ₃	a 26	_	C_5H_{11}
54	C_8H_{17}		a 4	a 4	_	C ₈ H ₁₇
55	C_3H_7		a 4	a ₂₆	0	$C_{10}H_{21}$
56	C ₇ H ₁₅	_	a 5	a 5	_	C_6H_{13}
57	C ₅ H ₁₁	0	a 5	a 5	_	C ₅ H ₁₁
58	C_3H_7	О	a ₅	a 5		$C_{11}H_{23}$
59	Н	_	a ₅	a 5	0	C ₁₆ H ₃₃
60	C ₉ H ₁₉	0	a ₅	a 5	0	C ₇ H ₁₅

Table 8

	No.	R	X	A	В	X'	R'
	61	C ₆ H ₁₃		a 5	аб	-	C ₆ H ₁₃
5	62	C ₇ H ₁₅		аь	а _б		C_7H_{16}
	63	C ₈ H ₁₇	_	аб	аб	-	C ₈ H ₁₇
	64	C ₁₃ H ₂₇	_	a ₅	аб	_	$C_{5}H_{11}$
	65	$C_{10}H_{21}$	_	a ₅	a ₂₆	0	$(CH_2)_5C \equiv CCH_3$
	66	C_4H_9	_	a ₅	a ₂₆	_	C ₉ H ₁₉
	67	C_5H_{11}		a ₅	a ₂₆		C_5H_{11}
10	68	C ₆ H ₁₃		a 6	a 6		C ₆ H ₁₃
	69	C ₁₂ H ₂₅		a 6	a ₆		C ₁₂ H ₂₅
	70	C_9H_{19}	_	a 6	a ₂₆	0	C ₃ H ₇
	71	$C_{10}H_{21}$		a 6	a 26	_	C ₁₀ H ₂₁
	72	C_3H_7	_	a 7	a 7		C ₃ H ₇
15	73	$C_{10}H_{21}$	_	a 7	a ₇	_	C ₄ H ₉
	74	$C_{11}H_{23}$	_	a 7	a 7	0	(CH ₂) ₇ CH(CH ₃) ₂
	75	C ₁₇ H ₃₅	0	a 7	a 7		C ₈ H ₁₇
	76	C ₇ H ₁₅		a 7	a 7	_	C ₇ H ₁₅
	77	C ₈ H ₁₇	_	a 7	a 7		C ₈ H ₁₇
20	78	C ₉ H ₁₉		a 7	a ₇		C ₉ H ₁₉
20	79	C ₁₀ H ₂₁	_	a 7	a ₇		C ₁₀ H ₂₁
	80	$C_{11}H_{23}$	_	аγ	ал		C ₃ H ₇

Table 9

No.	R	X	Α	В	X'	R'
81	C7H16		ал	a ₂₆	0	CH ₃
82	C ₇ H ₁₅	_	a 7	a ₂₆	OOC	C₄H ₉
83	C ₈ H ₁₇	_	a ₇	a ₂₆	_	C ₈ H ₁₇
84	C ₇ H ₁₅	_	a 8	a 8	-	$\mathrm{C_{7}H_{15}}$
85	C ₈ H ₁₇	-	a 8	a 8	-	C_8H_{17}
86	$C_{12}H_{25}$	-	a 8	a ₂₆	0	C_5H_{11}
87	$C_{18}H_{37}$	_	a 8	a ₂₆	_	C₄H ₉
88	C ₇ H ₁₅		a ₉	a ₉	_	C ₇ H ₁₅
89	C_8H_{17}	_	a ₉	a ₉	-	C ₈ H ₁₇
90	C_9H_{19}	_	a ₉	a 9	_	C ₉ H ₁₉
91	C_4H_9		a ₉	a ₉	-	C₄H ₉
92	$C_{15}H_{31}$	_	a ₉	a ₉	_	$C_{15}H_{31}$
93	C ₅ H ₁₁		a ₉	a ₉	_	C ₈ H ₁₇
94	$C_{10}H_{21}$	_	a ₉	a ₉		C_6H_{13}
95	C_6H_{13}	-	a ₉	a ₂₆	COO	(CH ₂) ₃ OC ₃ H ₇
96	C_9H_{19}	_	a ₉	a ₂₆		C ₉ H ₁₉
97	C ₇ H ₁₅	_	a 10	a 10	0	C ₆ H ₁₃
98	C ₇ H ₁₅	_	a 10	a 10	_	C ₇ H ₁₅
99	$C_{10}H_{21}$	_	a 10	a 10		C ₁₀ H ₂₁
100	$C_{5}H_{11}$	_	a ₁₀ .	a ₂₆	0	C ₁₁ H ₂₃

Table 10

No.	R	X	A	В	X'	R'
101	C ₈ H ₁₇	_	a 10	a 26	-	$C_{12}H_{25}$
102	C ₈ H ₁₇	_	a 11	a 11	-	C ₈ H ₁₇
103	C ₉ H ₁₉		a 11	a 11	_	C ₉ H ₁₉
104	C_3H_7	0	a 11	a 11		C ₈ H ₁₇
105	C ₁₈ H ₃₇	0	a 11	a 26	О	C_2H_5
106	C_6H_{13}	_	a ₁₂	a ₁₂		. C ₆ H ₁₃
107	C_9H_{19}	<u>.</u>	a 12	a ₁₂		C ₉ H ₁₉
108	$C_{10}H_{21}$	-	a ₁₂	a ₁₂		C ₁₀ H ₂₁
109	$C_{11}H_{23}$	_	a ₁₂	a 12	<u>-</u>	C ₁₁ H ₂₃
110	$C_{12}H_{25}$	_	a 12	a ₁₂		C ₁₂ H ₂₅
111	C ₇ H ₁₅	_	a ₁₂	a ₂₆	0	C ₅ H ₁₁
112	$C_{13}H_{27}$	_	a 12	a 26		$C_{10}H_{21}$
113	C_4H_9		a 13	a ₁₃	_	C_4H_9
114	C ₉ H ₁₉		a ₁₃	a ₁₃	S	C ₈ H ₁₇
115	C ₅ H ₁₁	_	a 14	a 14		C ₅ H ₁₁
116	C ₇ H ₁₅	0	a 14	a 14		C ₉ H ₁₉
117	$C_{10}H_{21}$	_	a 14	a 33	0	(CH ₂) ₃ OC ₅ H ₁₁
118	C ₇ H ₁₅	T -	a 14	a 33	_	C ₇ H ₁₅
119	$C_{12}H_{25}$	_	a 14	a 33		C ₁₂ H ₂₅
120	C ₈ H ₁₇	-	a 14	a 26		C ₄ H ₉

Table 11

No.	R	X	A _	В	Χ'	R!
121	C ₆ H ₁₃	_	a 14	a ₂₆		C ₅ H ₁₃
122	C ₃ H ₇	_	a 33	a ₁₄	_	C ₁₅ H ₃₁
123	C ₈ H ₁₇	-	a 33	a ₂₆	0	C ₈ H ₁₇
124	C ₃ H ₇	0	a ₁₅	a ₁₅	_	C ₁₀ H ₂₁
125	C ₇ H ₁₅	_	a 15	a ₁₅	_	C ₇ H ₁₅
126	C_5H_{11}	_	a 15	a ₁₅	0	C ₇ H ₁₅
127	C_4H_9	_	a ₁₅	a 15		C ₄ H ₉
128	$C_{5}H_{11}$		a ₁₅	a 15	_	C_5H_{11}
129	C ₆ H ₁₃	_	a ₁₅	a ₁₅		C ₆ H ₁₃
130	C ₇ H ₁₅		a ₁₅	a 15	_	C₁H₁₅
131	C ₈ H ₁₇		a 15	a 15	_	C ₈ H ₁₇
132	C ₁₂ H ₂₅		a 15	a 15		C ₃ H ₇
133	Н	_	a 15	a 26	. 0	C ₁₆ H ₃₃
134	$C_{10}H_{21}$		a 15	a 26		C ₁₀ H ₂₁
135	C ₈ H ₁₇		a 16	a 16	_	C ₈ H ₁₇
136	$C_{18}H_{37}$	_	a 16	a 16		C ₁₈ H ₃₇
137	C ₆ H ₁₃	_	a 16	a 26		C ₆ H ₁₃
138	$C_{11}H_{23}$		a 16	a 26	0	C_2H_5
139	$C_8H_{17}C\equiv C$	0	a 17	a 17	_	$C_{10}H_{21}$
140	C ₉ H ₁₉		a 17	a 18	0	C ₃ H ₇

Table 12

No.	R	X	Α	В	X'	R'
141	C ₇ H ₁₅	-	a 17	a 17	-	C ₇ H ₁₅
142	C ₈ H ₁₇	_	a ₁₇	a 17	[C ₈ H ₁₇
143	C ₉ H ₁₉	_	a 17	a 17	_	C_9H_{19}
144	$C_{10}H_{21}$	_	a ₁₇	a 26	_	$C_{10}H_{21}$
145	C ₅ H ₁₁	_	a 18	a ₁₈	_	C ₅ H ₁₁
146	C ₇ H ₁₅	_	a 18	a ₂₆	0	$C_{12}H_{25}$
147	C ₈ H ₁₇	_	a ₁₉	a ₁₉		C ₈ H ₁₇
148	C ₄ H ₉		a 19	a ₁₉	_	C ₄ H ₉
149	C ₇ H ₁₅	_	a 19	a 19		$\mathrm{C_7H_{15}}$
150	C ₁₀ H ₂₁	_	a 19	a 19		C ₁₀ H ₂₁
151	C_8H_{17}	_	a 19	a 26	0	C ₁₀ H ₂₁
152	C ₇ H ₁₅	_	a ₁₉	a 26		C_7H_{15}
153	C ₉ H ₁₉	_	a 20	a 20		C ₉ H ₁₉
154	$C_{12}H_{25}$	_	a 20	a 20		C ₅ H ₁₁
155	C ₈ H ₁₇	_	a 21	a 21		C ₈ H ₁₇
156	C ₆ H ₁₃	0	a 21	a 21	_	$C_{11}H_{23}$
157	$C_{10}H_{21}$		a 21	a 21	0	C ₄ H ₉
158	C ₅ H ₁₁		a 21	a 21		$C_{5}H_{1}$
159	C ₁₁ H ₂₃	_	a 21	a 21		C ₁₁ H ₂₃
160	C_4H_9	_	a 21	a 26	0	C ₁₂ H ₂₅

Table 13

				a management over		
No.	R	X	Α	В	Χ'	R'
161	C ₁₉ H ₃₉		a 21	a 26	_	Н
162	C ₁₃ H ₂₇	_	a ₂₂	a 20		$\mathrm{C_3H_7}$
163	C ₇ H ₁₅	_	a 22	a _{2t} ;	-	C ₇ H ₁₅
164	C_5H_{11}	_	a ₂₃	a ₂₃		C ₅ H ₁₁
165	C ₇ H ₁₅	_	a ₂₃	a ₂₃	_	$C_{7}H_{15}$
166	$C_{10}H_{21}$	_	a ₂₃	a ₂₃	_	$C_{10}H_{21}$
167	C ₄ H ₉	_	a ₂₃	a ₂₃	-	C_9H_{19}
168	$C_{12}H_{25}$		a ₂₃	a 26	0	(CH ₂) ₇ CH(CH ₃)OC ₂ H ₅
169	C_3H_7	_	a 24	a ₂₄	_	$\mathrm{C_3H_7}$
170	C ₆ H ₁₃	_	a ₂₄	a ₂₄	-	C_6H_{13}
171	C_7H_{15}	-	a ₂₄	a 24	_	$\mathrm{C_7H_{15}}$
172	C_8H_{17}	_	a ₂₄	a ₂₄		C_8H_{17}
173	$C_{11}H_{23}$	_	a 24	a ₂₄	_	$C_{11}H_{23}$
174	C_9H_{19}	_	a 24	a ₂₆	0	C_5H_{11}
175	C_6H_{13}	_	a ₂₅	a ₂₄	_	$\mathrm{C_4H_9}$
176	$C_{17}H_{35}$		a 25	a ₂₅	_	C ₁₇ H ₃₅
177	C ₇ H ₁₅	0	a ₂₇	a 27	_	C ₇ H ₁₅
178	C ₈ H ₁₇		a 28	a ₂₆		C ₉ H ₁₉
179	CH ₃	_	a 29	a 4	_	$C_{10}H_{21}$
180	C ₉ H ₁₉	0	a 30	a 30	_	$C_{11}H_{23}$

Table 14

						•
No.	R	X	Α	В	X'	R'
181	C_4H_9		a 31	a ₂₅	_	C ₁₂ H ₂₅
182	$C_{15}H_{31}$	_	a 32	a ₂₆		$C_{15}H_{31}$
183	C_8H_{17}	_	a ₁	a 4	_	C ₈ H ₁₇
184	C_5H_{11}		a ₁	a 6	_	C ₅ H ₁₁
185	$C_{12}H_{25}$	_	a ₁	a 6	_	$C_{12}H_{25}$
186	C ₇ H ₁₅	_	a ₁	a 7		C ₇ H ₁₅
187	$C_{5}H_{11}$	_	a ı	a ₈	_	$C_{11}H_{23}$
188	C_9H_{19}	-	a ₁	a ₉		C ₉ H ₁₉
189	C_6H_{13}	-	a 1	a 10		C ₆ H ₁₃
190	C_4H_9	_	a ₁	a 14		C ₄ H ₉
191	C ₇ H ₁₅		a i	a 16	_	C ₇ H ₁₅
192	$C_{11}H_{23}$	_	a ₁	a 18	_	C ₁₁ H ₂₃
193	C ₈ H ₁₇	_	a ₁	a ₂₅		C ₉ H ₁₉
194	C_6H_{11}	_	аз	a 6		C ₅ H ₁₁
195	$C_{10}H_{21}$	_	a 7	a 10		C_3H_7
196	C ₆ H ₁₃	_	a 7	a 22	_	C ₆ H ₁₃
197	C ₇ H ₁₅	_	a 14	a 18	_	C ₁₀ H ₂₁
198	C_4H_9	_	a ₁₅	a 25	· —	C ₄ H ₉
199	C ₆ H ₁₃	_	a ₁	a ₂₅		C_5H_{11}
200	C ₈ H ₁₇	_	a 24	a 26		C ₈ H ₁₇

Table 15

	T_ T	R	X	A	В	Χ'	R'
	lo.						$C_2H_5OC_3H_6$
2	01	$\frac{\mathrm{C_2H_5OC_3H_6}}{-}$		a ₁	a 1		
2	202	$C_3H_7OC_3H_6$		a ₁	a 1		C ₃ H ₇ OC ₃ H ₆
2	203	$C_4H_9OC_3H_6$	_	a ₁	a ₁		$C_4H_9OC_3H_6$
2	204	(CH ₃) ₂ CHCH ₂ CH ₂ CH ₂	_	a ₁	a 1	_	CH ₂ CH ₂ CH ₂ CH(CH ₃) ₂
2	205	(CH ₃) ₂ CHCH ₂ CH ₂ CH ₂ CH ₂	· —	a ₁	a 1		CH ₂ CH ₂ CH ₂ CH ₂ CH(CH ₃) ₂
2	206	CH ₃ CH ₃ CH ₂ CHCH ₂ CH ₂ CH ₂	_	a ₁	a 1		CH ₃ CH ₂ CH ₂ CH ₂ CHCH ₂ CH ₃

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In a preferred embodiment, the structural isomer mixture (comprising a plurality of organic compounds) used in the present invention may suitably be prepared by reacting two mono-substituted cyclic compounds (monomers) each having a plurality of reaction sites (positions) with each other or by effecting dimerization of one mono-substituted cyclic compound having a plurality of reaction sites.

The thus-prepared structural isomer mixture includes a major component (structural-isomer) and a minor component (structural isomer) in a (major component)/(minor component) ratio of 1/1 to 9/1, particularly 1/1 to 5/1.

In the electroconductive device of the present invention, the electroconductive layer comprising the above-mentioned structural isomer mixture is disposed between a pair of oppositely disposed electrodes, thus improving current and device characteristics. The electroconductive layer allows a high joint efficiency with metal and a high (carrier) mobility, so that the resultant electroconductive device is applicable to various semiconductor devices. The structure of the pair of electrodes may appropriately be changed depending on characteristics and structures of the semiconductor devices used.

In the EL device of the present invention, the electroconductive layer of structural isomer

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mixture is used as a carrier injection layer and/or a carrier transport layer, thus improving carrier injection and/or transport performances from the electrodes to ensure a good luminescent characteristic.

The EL device according to the present invention has a principal structure wherein a luminescence layer and the electroconductive layer of structural isomer mixture (as the carrier injection layer and/or the carrier transport layer as described above) are disposed between a pair of oppositely disposed electrodes as shown in Figures 6 and 7.

Referring to Figures 6 and 7, materials for the transparent substrate 21, anode (transparent electrode) 22, luminescence layer 24 and cathode (metal electrode) 25 may be known ones.

More specifically, the anode 22 may be formed of a transparent conductive material having a larger work function, preferably ITO (indium tin oxide) or IZO (indium zinc oxide). ITO may preferably contain 1 - 30 wt. % of SnO₂ per In₂O₃, and IZO may preferably contain 5 - 30 wt. % of ZnO per In₂O₃, so as to provide a lower electric resistance. The anode 22 may also be formed of other materials, such as indium oxide, tin oxide, Cd₂SnO₄, zinc oxide, copper iodide, gold and platinum.

The cathode 25 may be formed of a material

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(metal, alloy or compound) having a smaller work function by (vacuum) vapor deposition or sputtering. Examples of the material for the cathode 25 may include i metals, such as K, Li, Na, Mg, Ka, Ce, Ca, Cr and Ba; compounds, such as BaO, BaS, CaO, HfC, LaB6 MgO, MoC, NbC, PbS and SiO; and alloys of Al-Ca (Ca = 1 - 30 wt. %) and Al-Li (Li = 0.5 - 10 wt. %), in order to improve stability.

The luminescence layer 24 may be formed of Alq 3 (tris(8-quinolinato)aluminum), BeBq (bis(benzoquinolinolato)beryllium complex), DTVBi (4.4'-bis-(2.2-di-p-tolyl-vinyl)-biphenyl), Eu (DBM)? (Phen) (tris(1,3-diphenyl-1,3-propanediono) (monophenanthroline) Eu (III), diphenylethylene derivatives, triphenylamine derivatives, 15 diaminocarbazole derivatives, bisstyryl derivatives, benzothiazole derivatives, benzoxazole derivatives, aromatic diamine derivatives, quinacridone compounds, perylene compounds, oxadiazole compounds, coumarin compounds, and anthraquinone compounds. 20 materials may preferably be formed in a layer in an amorphous state by vacuum (vapor) deposition.

The electroconductive layer formed of the above-mentioned structural isomer mixture is used as at least one layer of a hole transfer layer 23 (shown 25 in Figures 6 and 7), an electron transport layer 31 (shown in Figures 6 and 7), a hole injection layer

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(not shown) and an electron injection layer (not shown). These carrier injection and transport layers other than the electroconductive layer may be formed of known materials.

In the EL device of the present invention, electroconductive layer of structural isomer mixture may particularly preferably be used as the electron\injection layer. More specifically, in an ordinary EN device, it is generally difficult to effect injection of electrons from the cathode into the organic compound layer(s) compared with injection of holes from the anode into the organic compound This may be attributable to difficulty of layer(s). decreasing a work function of a metal (used for the metal (cathode) electrode) compared with LUMO level of the organic material used, due to lower stability of the metal material. Accordingly, in the EL device having such a structure that one or plural organic compound layers (films) are disposed between the cathode and the anode, the electroconductive layer of structural isomer mixture may effectively used as the electron injection layer, thus allowing use of a material having a molecular structure with a high planarity (which cannot be conventionall) used due to crystallization of its deposited film) to give more latitude in selection of material used.

The hole transport layer may be formed of an

electron-donating material, such as triphenyldiamine derivatives (a representative example thereof may include α -NPD (bis[N-(1-naphthyl)-N-phenyl]benzidine) shown hereinafter). Examples of the hole injection layer material may include tetraarylbenzidine compounds (triphenyldiamine), hydrazone derivatives, carbazole derivatives, triazole derivatives, imidazole derivatives, oxadiazole derivatives and polythiophene.

In the case of forming the electron injection layer, a material therefor may include quinoline derivatives (such as Alq3 described above), oxadiazole derivatives and perylene derivatives.

Hereinbelow, the present invention will be described more specifically based on Examples.

15 Example 1 (Synthesis of Ex. Comp. No. 19)

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In a 2 liter-round bottomed flask, 64 g (371.1 mM) of 1,2-diamino-4-hexylbenzene (a) and 49.5 g (412.1 mM) of 1,4-dioxane-2,3-diol (b) were placed and dissolved in 793 ml of ethanol, followed by stirring overnight at room temperature.

After the reaction, the reaction mixture was subjected to distilling-off of the solvent under

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reduced pressure and purified by silica gel column chromatography (eluent: toluene/ethyl acetate = 1/4), followed by distilling-off of the solvent under reduced pressure to obtain 53.3 g of 6-hexyl-quinoxaline (e).

In a 200 ml-round bottomed flask, 53.3 g (248.7 mM) of 6-hexylquinoxaline (c), 31 g (258.8 mM) of pyridine-1-oxide and 20 g of palladium-carbon were placed and heat-refluxing overnight under stirring.

After cooling, the reaction mixture was subjected to filtration, followed by distilling-off of the solvent under reduced pressure to obtain a residue. The residue was washed with ethanol and subjected to filtration, followed by recrystallization from

pyridine to obtain a crude product. The crude product was dissolved in chloroform and filtered with alumina. The filtrate was recrystallized from toluene to obtain 10.4 g of structural isomer mixture (2,2'-bihexyl-quinoxaline ((d1)/(d2)/(d3) = 1/2/1); Ex. Comp. No. 19).

The structural isomer mixture showed the following phase transition series.

Phase transition temperatures (OC)

10 Crystal 154.5 Isotropic phase 134.4

The above-prepared structural isomer mixture (Ex. Comp. No. 19) and two comparative compounds (Comparative Compounds 1 and 2) were evaluated in terms of crystallization characteristic in the following manner.

Each compound was formed in a 20 nm-thick film by vacuum (vapor) deposition and observed at 30 °C, thus determining a time required to cause crystallization.

The results are shown in Table 16.

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Table 16

Ex. Comp.No.	Formula	Crystallization (Hr at 30°C)
	C_6H_{13} $N=N$ $N=N$	C_6H_{13}
19	C ₆ H ₁₃ —N—N—N—N—N—N—N—N—N—N—N—N—N—N—N—N—N—N—N	>72
	C ₆ H ₁₃	C ₆ H ₁₃
		C ₆ H ₁₃
Comparative compound 1	C ₆ H ₁₃ —N	12 N————————————————————————————————————
Comparative	/=\	0
	N-	

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As shown in Table 16, compared with monomolecular compounds (Comparative Compounds 1 and 2), the structural isomer mixture (Ex. Comp. No. 19) provided a stable amorphous structure.

5 Example 2

An organic EL device (electroconductive device) having a sectional structure as shown in Figure 1 was prepared by using the structural isomer mixture (Ex. Comp. No. 19) prepared in Example 1 in the following manner.

On a 1 mm-thick glass substrate 11, a 70 nm-thick ITO (indium tin oxide) film was formed as an anode (ITO electrode) 12 by sputtering and ultraviolet-light irradiation for surface treatment (cleaning).

The above-treated substrate 11 having the ITO film (anode) 12 was placed in a vacuum chamber held at a pressure of ca. 1.33×10^{-3} Pa (ca. 1×10^{-5} Torr), and a 50 nm-thick layer of α -NPD (bis[N-(1-naphthyl)-N-phenyl]benzidine) represented by a formula shown below was formed on the ITO film 12 as a hole (carrier) transporting layer 13 by (resistance heating) vacuum deposition at a rate of 0.1 nm/sec.

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 α -NPD

Under similar vacuum deposition conditions, three organic layer segments (luminescence layer segments) 14 exhibiting different luminescent wavelengths were respectively formed in a thickness of 50 nm on the hole transporting layer 13 by vacuum deposition. The three organic layer (luminescence layers) 14a - 14c were respectively formed of (95 wt. % of) Alq3 of a formula (a) shown below doped with 5 wt. % of perylene of a formula (b) shown below for shifting the luminescence wavelength to a shorter wavelength side, (95 wt. % of) Alq3 of the formula (a) doped with 5 wt. % of DCM (a styryl dye) of a formula (c) shown below for shifting the luminescence wavelength to a longer wavelength side, and Alq3 alone (providing a center luminescence wavelength).

On each of the luminescence layers 14a - 14c, a 20 nm-thick layer of a structural isomer mixture (Ex. Comp. No. 19) was formed as an electron (carrier) injection layer 16 by vacuum deposition.

The thus-formed electron injection layer

(structural isomer mixture layer) 16 was coated with a lamination-type cathode metal layer as a cathode electrode 15 each comprising a 10 nm-thick layer of Al-Li alloy (Al/Li = 98.2/1.8 by weight) and a 150 nm-thick Al layer, respectively, formed by vacuum deposition to prepare an organic EL device as shown in Figure 1.

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(b) perylene

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The thus-prepared EL device was subjected to

25 measurement of a current-voltage characteristic and a

luminescence efficiency at room temperature at a

portion containing the luminescence layer 14c

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comprising Alq3 alone (i.e., free from the dopants of the formulas (b) and (c)) by using a microammeter ("4140B", mfd. by Hewlett-Packard Co.) and a luminance meter ("BM7", mfd. by Topcon K.K.), respectively.

The results are shown in Figures 2 and 4, respectively.

Referring to Figure 2, the resultant current-voltage curve showed that the EL device provided a good rectifying performance and a higher current density with respect to an applied electric field.

Further, as shown in Figure 4, it was also confirmed that the EL device provided a higher luminescence efficiency in proportion to the current density.

The higher current density may be attributable to improvement in electron injection efficiency (performance) by the use of the structural isomer mixture (Ex. Comp. No. 19 in this example) since the EL device provided the higher current density compared with that in Comparative Example 1 below although the EL device had a lower electric field intensity.

Comparative Example 1

An organic EL device was prepared and evaluated in the same manner as in Example 2 except that the electron injection layer 16 (of the structural isomer mixture (Ex. Comp. No. 19) was not formed.

The results (current-voltage characteristic and luminescence efficiency are shown in Figures 3 and 5, respectively.

Compared with Figure 2 (Example 2), although a higher electric field strength (a smaller organic compound layer thickness) was applied, the EL device (of Comparative Example 1) provided smaller current density values as shown in Figure 3, thus resulting in an inferior electron injection performance.

As described hereinabove, according to the gresent invention, by using the electroconductive layer formed of structural isomer mixture excellent in carrier in ection and/or transport characteristics, it is possible to apply the resultant electroconductive device to various devices including semiconductor devices, thus improving their characteristics. Particularly, the organic EL device according to the present invention wherein the electroconductive layer is used as a carrier in ection layer and/or a carrier transport layer provides Amproved luminescence efficiency and current-voltage characteristic, so that it is also possible to employ a thicker organic compound layer thereby to improve a reliability (e.g., prevention of occurrence of short-circuit between a pair of electrodes).

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